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DMV1500HD

Damper + modulation diode for CRT TV

Features

- Full kit in one package
- High breakdown voltage capability
- Very fast recovery diode
- Specified turn on switching characteristics
- Low static and peak forward voltage drop for low dissipation
- Insulated version:
 - Insulated voltage = 2000 V_{RMS}
 - Capacitance = 7 pF
- Planar technology allowing high quality and best electrical characteristics
- Outstanding performance of well proven DTV as damper and new faster Turbo 2 600 V technology as modulation

Description

High voltage semiconductor especially designed for horizontal deflection stage in standard and high resolution video display with E/W correction.

The insulated TO-220FPAB package includes both the damper diode and the modulation diode, thanks to a dedicated design.

Assembled on automated line, it offers very low dispersion values or, insulating and thermal performanes.

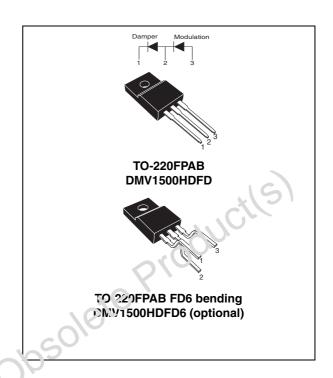


Table 1. Device summary

Symbol	Damper	Modulation
I _{F(AV)}	6 A	3 A
I _{Fpeak} (max)	12 A	12 A
V _{RRM}	1500 V	600 V
t _{rr} (typ)	150 ns	60 ns
V _F (typ)	1.0 V	1.0 V
V _{FP} (typ)	21 V	5 V

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Characteristics 1

Table 2. **Absolute maximum ratings**

Symbol	Paramete	Va	Value		
Symbol	i aramete	Damper	Modulation	Unit	
V_{RRM}	Repetitive peak reverse voltage		1500	600	V
I _{Fpeak}	Peak working forward current	F = 56 kHz	12	12	Α
I _{FSM}	Surge non repetitive forward current	t _p = 10 ms sinusoidal	75	50	Α
T _{stg}	Storage temperature range		-40 to	+150	°C
T _i	Maximum operating junction temperature		150		°C

Table 3. Thermal resistance

Symbol		Value	Unit		
R _{th(j-c)}	Junction to case thermal resistance				°C/W
Table 4.	Static electrical chara		$\gamma \eta_{Cr}$		

Table 4. Static electrical characteristics

				Value						
Symbol	Parameter	Test conditions		Test conditions		T _j = 2	25 °C	T _j = 1	25 °C	Unit
				Тур.	Max.	Тур.	Max.			
ı (1)	I _R ⁽¹⁾ Reverse leakage current	Damper	V _R = 1500 V	10	100	100	1000	^		
'R`		Modulation	V _R = 600 V	(20	3	50	μΑ		
V (2)	V _F ⁽²⁾ Forward voltage drop	Damper	I _F = 6 A	1.5	2.3	1.25	1.7	V		
V _F (-)		Modulation	I _F = 3 A		1.8	1.1	1.4	V		

^{1.} Pulse test: $t_p = 5 \text{ ms}, \delta < 2\%$

To evaluate the maximum conduction losses of the **damper** and **modulation** diodes use the following equations :

Damper: $P = 1.05 \times I_{F(AV)} + 0.05 \times I_{F^2(RMS)}^2$ **Modulation**: $P = 0.89 \times I_{F(AV)} + 0.055 \times I_{F}^{2}_{(RMS)}$

Table 5. **Recovery characteristics**

		61				Va	lue		
Sym	bol	Parameter	Test conditions		Dan	nper	Modu	lation	Unit
10-					Тур.	Max.	Тур.	Max.	
		I _F = 100 mA I _R =100 mA I _{RR} = 10 mA	T _j = 25 °C	1000		250	400	ns	
t _{rr}	•	Reverse recovery time	$I_F = 1 \text{ A}$ $dI_F/dt = -50$ $A/\mu s V_R = 30 V$	T _j = 25 °C	150	250	60	85	115

^{2.} Pulse test: t_p = 380 μ s, δ < 2%

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Table 6. Turn-on switching characteristics

Symbol Parameter		Test conditions			Value		Unit
Cymbol	Tarameter		rest conditions			Max.	O TILL
+.	Forward recovery time	Damper	$I_F = 6 \text{ A}$ $dI_F/dt = 80 \text{ A/}\mu\text{s}$ $V_{FR} = 3 \text{ V}$	T _j = 100 °C	330	470	ns
t _{fr} Forward recovery time	Modulation	$I_F = 6 \text{ A}$ $dI_F/dt = 80 \text{ A/}\mu\text{s}$ $V_{FR} = 2 \text{ V}$	T _j = 100 °C	85	125	115	
V	V _{FP} Peak forward voltage	Damper	I _F = 6 A dI _F /dt = 80 A/μs	T _j = 100 °C	21	29	V
V _{FP}		Modulation	$I_F = 6 A$ $dI_F/dt = 80 A/\mu s$	T _j = 100 °C	5	7.5	V

Figure 1. Power dissipation vs. peak forward Figure 2. Average forward current vs. current (triangular waveform, ambient temperature δ = 0.45)

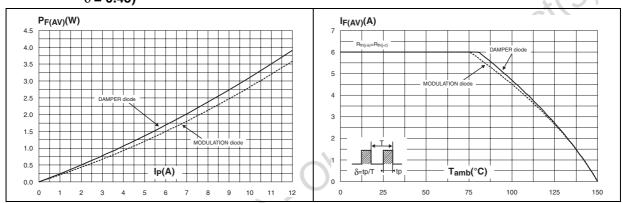
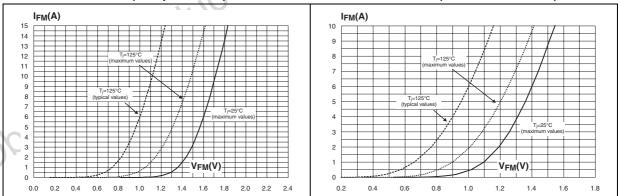


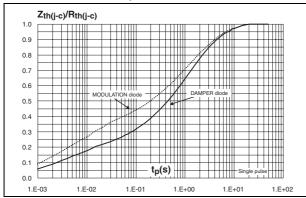
Figure 3. Forward voltage drop vs. forward Figure 4. Forward voltage drop vs. forward current (damper diode) current (modulation diode)



Characteristics DMV1500HD

Figure 5. Relative variation of thermal impedance junction to case versus pulse duration

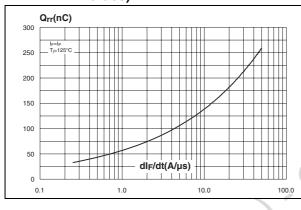
Figure 6. Reverse recovery charges vs. dl_F/dt (damper diode, typical values)



Qrr(µC)
4.0
3.5
T_{|F=|D|}
3.0
2.5
2.0
1.5
1.0
0.5
0.0
0.1
1.0
10.0
100.0

Figure 7. Reverse recovery charges vs. dl_F/dt (modulation diode, typical values)

Figure 8. Peak reverse recovery current vs. dl_F/dt (damper diode, typical values)



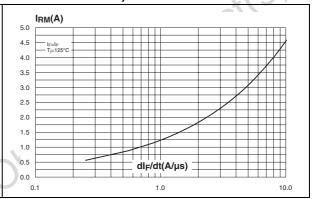
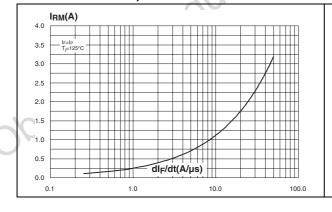
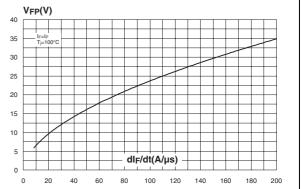


Figure 9. Peak reverse recovery current vs. dl_F/dt (modulation diode, typical values)

Figure 10. Transient peak forward voltage vs. dl_F/dt (damper diode, typical values)





DMV1500HD Characteristics

Figure 11. Transient peak forward voltage vs. Figure 12. Forward recovery time vs. dl_F/dt dl_F/dt (modulation diode, typical values)

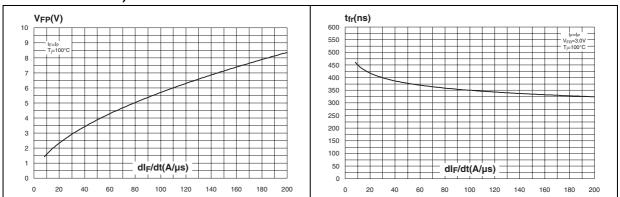


Figure 13. Forward recovery time vs. dl_F/dt (modulation diode, typical values)

Figure 14. Relative variation of dynamic parameters vs. junction temperature

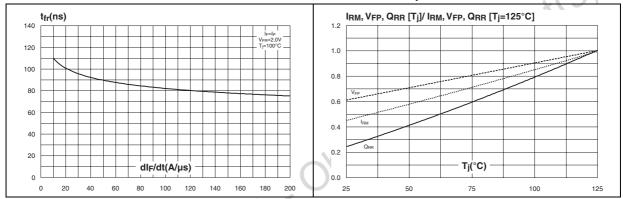
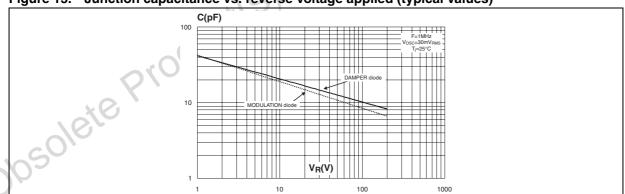


Figure 15. Junction capacitance vs. reverse voltage applied (typical values)



Package information DMV1500HD

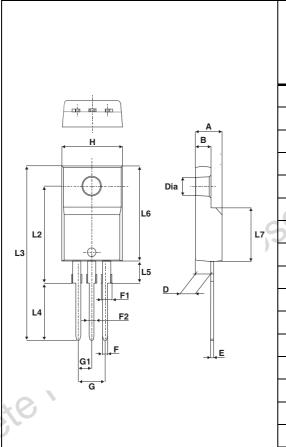
2 Package information

Epoxy meets UL94,V0

Recommended torque: 0.4 to 0.6 N⋅m

In order to meet environmental requirements, ST offers these devices in ECOPACK® packages. These packages have a lead-free second level interconnect. The category of second level interconnect is marked on the package and on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an ST trademark. ECOPACK specifications are available at www.st.com

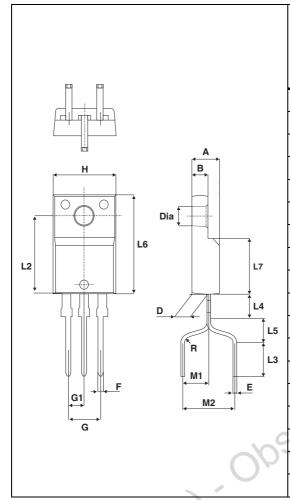
Table 7. TO-220FPAB dimensions



	Dimensions					
Ref.	Millim	neters	Inches			
	Min.	Max.	Min.	Max.		
Α	4.4	4.6	0.173	0.181		
В	2.5	2.7	0.098	0.106		
D	2.5	2.75	0.098	0.108		
Ш	0.45	0.70	0.018	0.027		
F	0.75	1	0.030	0.039		
F1	1.15	1.50	0.045	0.059		
F2	1.15	1.50	0.045	0.059		
G	4.95	5.20	0.195	0.205		
G1	2.4	2.7	0.094	0.106		
Η	10	10.4	0.393	0.409		
L2	16	Тур.	0.63	Тур.		
L3	28.6	30.6	1.126	1.205		
L4	9.8	10.6	0.386	0.417		
L5	2.9	3.6	0.114	0.142		
L6	15.9	16.4	0.626	0.646		
L7	9.00	9.30	0.354	0.366		
Dia.	3.00	3.20	0.118	0.126		

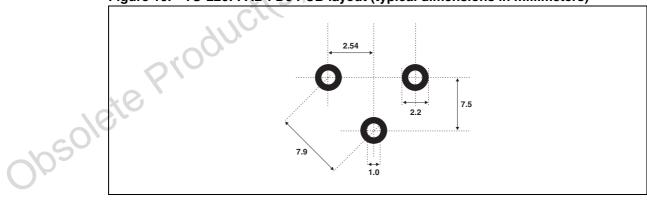
DMV1500HD Package information

Table 8. TO-220FPAB F6 dimensions



	Dimensions					
Ref.	Millim	neters	Inches			
	Min.	Max.	Min.	Max.		
Α	4.4	4.9	0.173	0.192		
В	2.5	2.9	0.098	0.114		
D	2.45	2.75	0.096	0.108		
Е	0.4	0.7	0.016	0.028		
F	0.6	1	0.024	0.039		
G	4.8	5.3	0.195	0.205		
G1	2.2	2.95	0.094	0.106		
Н	10	10.7	0.394	0.421		
L2	12.7	12.8	0.500	0.504		
L3	4.8	Тур.	0.189 Typ.			
L4	3.4	4.8	0.150	0.165		
L5	2.9	Тур.	0.114	¥ Тур.		
L6	15.8	16.4	0.622	0.646		
L7	9	9.9	0.354	0.390		
M1	3.75	Тур.	0.148	3 Тур.		
M2	7 8		0.276	0.315		
R	1 T	yp.	0.039	Тур.		
Dia.	2.9	3.5	0.114	0.138		

Figure 16. TO-220FPAB FD6 PCB layout (typical dimensions in millimeters)



Ordering information DMV1500HD

3 Ordering information

Table 9. Ordering information

Order code	Marking	Package	Weight	Base qty	Delivery mode
DMV1500HDFD	DMV1500HD	TO-220FPAB	2.4 g	50	Tube
DMV1500HDFD6	DMV1500HD	TO-220FPAB F6	2.4 g	45	Tube

4 Revision history

Table 10. Document revision history

	Date	Revision	Changes
	16-Mar-2005	1	Initial release.
	02-Dec-2008	2	Reformatted to current standards. Updated ECOPACK statement. Updated dimension illustration for TO-220FPAB FD6 in <i>Table 8</i> .
Obsole	te Pro	ductl	S) Obsolete Prov

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